

# Laser Printer System Frequency Synthesizer

#### **Features**

- Maximized EMI suppression using Cypress's Spread Spectrum technology
- Reduces measured EMI by as much as 10dB
- · Four skew-controlled copies of CPU output
- · Four skew-controlled copies of SDRAM output
- One copy of 14.31818 MHz Reference output
- One copy of 48 MHz USB clock (not spread)
- Selectable SSFTG modulation width
- Available in 28-pin SSOP (209 mil)

#### **Key Specifications**

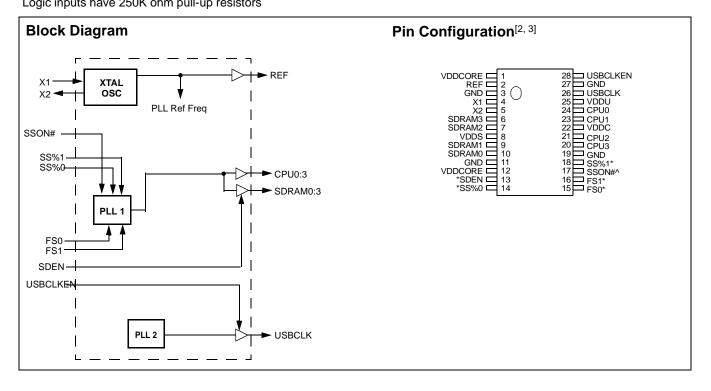
Supply Voltage: VDDCORE:	3.3V±10%
VDDC:	3.3V±10% or 2.5V±5%
VDDS:	3.3V±10% or 2.5V±5%
VDDU:	3.3V±10% or 2.5V±5%
CPU Clock Cycle to Cycle Jitter:	250 ps
USBCLK Long term Jitter:	± 500 ps
CPU0:3 Clock Skew:	250 ps
CPU, SDRAM Output on Resistant	ce:15Ω
Logic inputs have 250K ohm pull-	up resistors

#### Table 1. Pin Selectable Frequency<sup>[1]</sup>

FS1	FS0	CPU(0:3), SDRAM(0:3)	USBCLK
0	0	133.3 MHz	48 MHz
0	1	100MHz	48 MHz
1	0	66.6MHz	48 MHz
1	1	50MHz	48 MHz

#### **Table 2. Spread Characteristics**

SSON#	SS%1	SS%0	CPU(0:3), SDRAM(0:3)
0	0	0	-0.5%
0	0	1	-1.0%
0	1	0	-2.5%
0	1	1	-3.75%
1	0	0	0 (off)\
1	0	1	0 (off)
1	1	0	0 (off)
1	1	1	0 (off)



#### Notes:

All clock output loaded with maximum lump capacitance test load specified in AC Electrical Characteristics section. Signals marked with [\*] has internal pull-up resistors Signal marked with[^] has internal pull-down resistors.

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Cypress Semiconductor Corporation Document #: 38-07268 Rev. \*

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CA 95134 • 408-943-2600 Revised September 27, 2001



# **Pin Definitions**

Pin Name	Pin No.	Pin Type	Pin Description
CPU0:3	24, 23, 21, 20	0	<b>CPU Clock Outputs:</b> These four outputs run at a frequency set by FS0:1. The width of the Spread Spectrum Modulation is enabled by pin SSON#, and selected by pins SS%0:1.
SDRAM0:3	10, 9, 7, 6	0	<b>SDRAM Outputs:</b> These four SDRAM clock outputs run synchronously to the CPU clock. Modulation and frequency follow the CPU outputs.
FS0:1	15, 16	I	<i>Frequency Selection Inputs:</i> Selects CPU clock frequency as shown in <i>Table 1</i> .
SS%0:1	14, 18	I	<i>Modulation Width Selection Inputs:</i> These inputs select the width of the Spread Spectrum feature when it is enabled by SSON#.
USBCLK	26	0	<b>USB output:</b> Timing signal running at 48.0080 MHz when a 14.31818 MHz frequency is provided as the reference. (167 ppm accuracy to 48 MHz, the output is equal to the reference times 57/17.)
SSON#	17	I	<b>CPU Spread Spectrum Enable Input:</b> When this pin is pulled LOW, outputs CPU0:3 and SDRAM0:3 will have the Spread Spectrum Feature enabled.
USBCLKEN	28	I	<b>USB Disable Input:</b> When this pin is pulled LOW, output USBCLK will be disabled to a LOW state.
REF	2	0	<i>Reference output:</i> This output will be equal in frequency to the reference signal provided at X1/X2.
SDEN	13	I	<b>SDRAM Bank Disable Input:</b> When this pin is pulled LOW, outputs SDRAM0:3 will be disabled to a low state.
X1	4	I	<b>Crystal Connection or External Reference Frequency Input:</b> Connect to either a 14.318-MHz crystal or other reference signal.
X2	5	I	<i>Crystal Connection:</i> An input connection for an external 14.318-MHz crystal. If using an external reference, this pin must be left unconnected.
VDDCORE	1, 12	Р	Power Connection: Core Power supply. Connect to 3.3V supply.
VDDU	25	Р	<b>Power Connection:</b> Power supply for the USB output. Connect to 3.3V or 2.5V supply.
VDDC	22	Р	<b>Power Connection:</b> Power supply for the CPU outputs. Connect to 3.3V or 2.5V supply.
VDDS	8	Р	<i>Power Connection:</i> Power supply for the SDRAM outputs. Connect to 3.3V or 2.5V supply.
GND	3,11, 19, 27	G	<i>Ground Connections:</i> Connect all ground pins to the common system ground plane.



### **Spread Spectrum Generator**

The device generates a clock that is frequency modulated in order to increase the bandwidth that it occupies. By increasing the bandwidth of the fundamental and its harmonics, the amplitudes of the radiated electromagnetic emissions are reduced. This effect is depicted in *Figure 1*.

As depicted in *Figure 1*, a harmonic of a modulated clock has a much lower amplitude than that of an unmodulated signal. The reduction in amplitude is dependent on the harmonic number and the frequency deviation or spread. The equation for the reduction is

 $dB = 6.5 + 9*\log_{10}(P) + 9*\log_{10}(F)$ 

Where P is the percentage of deviation and F is the frequency in MHz where the reduction is measured.

The output clock is modulated with a waveform depicted in *Figure 2*. This waveform, as discussed in "Spread Spectrum Clock Generation for the Reduction of Radiated Emissions" by Bush, Fessler, and Hardin, produces the maximum reduction in the amplitude of radiated electromagnetic emissions. The deviation selected for this chip is  $\pm 0.5\%$  of the center frequency. *Figure 2* details the Cypress spreading pattern. Cypress does offer options with more spread and greater EMI reduction. Contact your local Sales representative for details on these devices.

Spread Spectrum clocking is activated or deactivated by selecting the appropriate values for bits 1–0 in data byte 0 of the SMBus data stream.

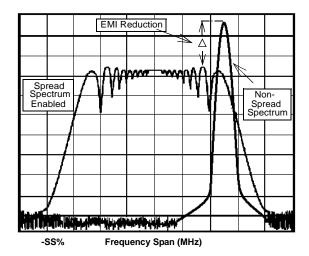


Figure 1. Clock Harmonic with and without SSCG Modulation Frequency Domain Representation

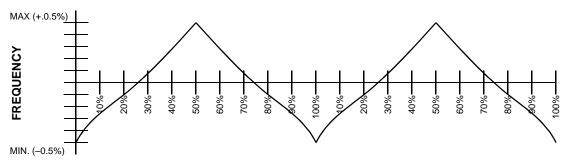


Figure 2. Typical Modulation Profile



### **Absolute Maximum Ratings**

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating

only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

Parameter	Description	Rating	Unit
V <sub>DD</sub> , V <sub>IN</sub>	Voltage on any pin with respect to GND	-0.5 to +7.0	V
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
T <sub>A</sub>	Operating Temperature	-55 to +125	°C
Τ <sub>B</sub>	Ambient Temperature under Bias	0 to +70	°C
ESD <sub>PROT</sub>	Input ESD Protection	2 (min)	kV

#### **DC Electrical Characteristics:**

 $T_A = 0^{\circ}C$  to +70°C,  $V_{DDQ3} = 3.3V \pm 10\%$ 

Parameter	Description	Test Condition	Min.	Тур.	Max.	Unit
Supply Curr	ent					
I <sub>DDQ3</sub>	Supply Current (3.3V)	CPUCLK =100 MHz Outputs Loaded <sup>[4]</sup>			400	mA
I <sub>DDQ2</sub>	Supply Current (2.5V)	CPUCLK =100 MHz Outputs Loaded <sup>[4]</sup>			400	mA
Logic Inputs	5					
V <sub>IL</sub>	Input Low Voltage		GND-3		0.8	V
V <sub>IH</sub>	Input High Voltage		2.0		V <sub>DD</sub> +.3	V
IIL	Input Low Current <sup>[5]</sup>				-25	μA
I <sub>IH</sub>	Input High Current <sup>[5]</sup>				10	μA
Crystal Osc	illator					
V <sub>TH</sub>	X1 Input Threshold Voltage <sup>[1]</sup>			1.5		V
C <sub>LOAD</sub>	Load Capacitance, Imposed on External Crystal <sup>[6]</sup>			14		pF
C <sub>IN,X1</sub>	X1 Input Capacitance <sup>[7]</sup>	Pin X2 unconnected		28		pF
	ance/Inductance					
C <sub>IN</sub>	Input Pin Capacitance	Except X1 and X2			5	pF
C <sub>OUT</sub>	Output Pin Capacitance				6	pF
L <sub>IN</sub>	Input Pin Inductance				7	nH

Notes:

CY24242 logic inputs have internal pull-up resistors.
X1 input threshold voltage (typical) is V<sub>DDQ</sub>/2.
The CY24242 contains an internal crystal load capacitor between pin X1 and ground and another between pin X2 and ground. Total load placed on crystal is 14 pF; this includes typical stray capacitance of short PCB traces to crystal.
X1 input capacitance is applicable when driving X1 with an external clock source (X2 is left unconnected).



### **AC Electrical Characteristics**

# $T_{A}$ = 0°C to +70°C, $V_{DD}$ = $V_{DDQ3}$ = 3.3V±10%, $f_{XTL}$ = 14.31818 MHz

AC clock parameters are tested and guaranteed over stated operating conditions using the stated lump capacitive load at the clock output.

			CPU = 66 MHz		CPU = 100 MHz				
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
t <sub>P</sub>	Period	Measured on rising edge at 1.5V	15		15.5	10		10.5	ns
t <sub>H</sub>	High Time	Duration of clock cycle above 2.4V	5.2			3.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	5			2.8			ns
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.4V	.4		3.2	.4		3.2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.4V to 0.4V	.4		3.2	.4		3.2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	45		55	%
t <sub>JC</sub>	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.5V. Max- imum difference of cycle time between two adjacent cycles.			250			250	ps
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.5V			250			250	ps
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cy- cles exist prior to frequency stabiliza- tion.			3			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transi- tion. Used for determining series ter- mination value.		20			20		Ω

### CPU Clock Outputs, CPU0:3 (Lump Capacitance Test Load = 20 pF, V<sub>DDC</sub> = 3.3V)

SDRAM Clock Outputs, SDRAM0:3 (Lump Capacitance Test Load = 30 pF, V<sub>DDC</sub> = 3.3V)

			CPU = 66 MHz		CPU = 100 MHz				
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
t <sub>P</sub>	Period	Measured on rising edge at 1.5V	15		15.5	10		10.5	ns
t <sub>H</sub>	High Time	Duration of clock cycle above 2.4V	5.2			3.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	5			2.8			ns
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.4V	.4		3.2	.4		3.2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.4V to 0.4V	.4		3.2	.4		3.2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	45		55	%
t <sub>JC</sub>	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.5V. Max- imum difference of cycle time between two adjacent cycles.			250			250	ps
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.5V		100	300		100	350	ps
t <sub>SK</sub>	CPU to SDRAM Clock Skew	Covers all CPU/SDRAM outputs. Mea- sured on rising edge at 1.5V.			350			350	ps
f <sub>ST</sub>	Frequency Stabiliza- tion from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transi- tion. Used for determining series termi- nation value.		20			20		Ω



#### REF Clock Outputs (Lump Capacitance Test Load = 20 pF)

			CP	CPU = 66/100MHz		
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Frequency equal to the reference pro- vided at pins X1, X2		14.318		MHz
t <sub>R</sub>	Output Rise Edge Rate		0.5		2	V/ns
t <sub>F</sub>	Output Fall Edge Rate		0.5		2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
f <sub>ST</sub>	Frequency Stabiliza- tion from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transi- tion. Used for determining series termi- nation value.		40		Ω

### USBCLK Clock Output (Lump Capacitance Test Load = 20 pF, $V_{DDC}$ =3.3V)

			CPU = 66/100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
t <sub>R</sub>	Output Rise Edge Rate		0.5		2	V/ns
t <sub>F</sub>	Output Fall Edge Rate		0.5		2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.5V	45		55	%
t <sub>JL</sub>	Jitter, Long term	Measured on rising edge at 1.5V. Maximum dif- ference of cycle time between two adjacent cy- cles.			500	
t <sub>JC</sub>	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.5V. Maximum dif- ference of cycle time between two adjacent cy- cles.			400	
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		40		Ω

### **Absolute Maximum Ratings**

Stresses greater than those listed in this table may cause permanent damage to the device. These represent a stress rating only. Operation of the device at these or any other conditions above those specified in the operating sections of this specification is not implied. Maximum conditions for extended periods may affect reliability.

Parameter	Description	Rating	Unit
V <sub>DD</sub> , V <sub>IN</sub>	Voltage on any pin with respect to GND	-0.5 to +7.0	V
T <sub>STG</sub>	Storage Temperature	-65 to +150	°C
T <sub>A</sub>	Operating Temperature	-55 to +125	°C
Τ <sub>B</sub>	Ambient Temperature under Bias	0 to +70	°C
ESD <sub>PROT</sub>	Input ESD Protection	2 (min)	kV



### **AC Electrical Characteristics**

# $T_{A}$ = 0°C to +70°C, $V_{DD}$ = $V_{DDQ3}$ = 2.5V $\pm$ 5%, $f_{XTL}$ = 14.31818 MHz

AC clock parameters are tested and guaranteed over stated operating conditions using the stated lump capacitive load at the clock output.

			CPU = 66 MHz		CPU = 100 MHz				
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Min.	Тур.	Max.	Unit
t <sub>P</sub>	Period	Measured on rising edge at 1.25V	15		15.5	10		10.5	ns
t <sub>H</sub>	High Time	Duration of clock cycle above 2.0V	5.2			3.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	5			2.8			ns
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0V	.4		3.2	.4		3.2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	.4		3.2	.4		3.2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	45		55	%
t <sub>JC</sub>	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.25V. Maximum difference of cycle time be- tween two adjacent cycles.			250			250	ps
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.25V			250			250	ps
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cy- cles exist prior to frequency stabiliza- tion.			3			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transi- tion. Used for determining series ter- mination value.		20			20		Ω

### CPU Clock Outputs, CPU0:3 (Lump Capacitance Test Load = 20 pF, V<sub>DDC</sub> = 2.5V)

SDRAM Clock Outputs, SDRAM0:3 (Lump Capacitance Test Load = 30 pF, V<sub>DDC</sub> = 2.5V)

			CPU = 66 MHz		CPU = 100 MHz				
Parameter	Description	Test Condition/Comments		Тур.	Max.	Min.	Тур.	Max.	Unit
t <sub>P</sub>	Period	Measured on rising edge at 1.25V	15		15.5	10		10.5	ns
t <sub>H</sub>	High Time	Duration of clock cycle above 2.0V	5.2			3.0			ns
tL	Low Time	Duration of clock cycle below 0.4V	5			2.8			ns
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0V	.4		3.2	.4		3.2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	.4	.4 3.2		.4		3.2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45	45 55		45		55	%
t <sub>JC</sub>	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.25V. Max- imum difference of cycle time between two adjacent cycles.	250				250	ps	
t <sub>SK</sub>	Output Skew	Measured on rising edge at 1.25V		250 300			250	350	ps
f <sub>ST</sub>	Frequency Stabiliza- tion from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.	3				3	ms	
Z <sub>o</sub>	AC Output Impedance	Average value during switching transi- tion. Used for determining series termi- nation value.20		20		Ω			



# REF Clock Outputs (Lump Capacitance Test Load = 20 pF)

Parameter Description			CP			
		Test Condition/Comments	Min.	Тур.	Max.	Unit
f	Frequency, Actual	Frequency equal to the reference pro- vided at pins X1, X2			MHz	
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0	0.5 2		2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	o 0.4V 0.5 2		2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45 55		%	
f <sub>ST</sub>	Frequency Stabiliza- tion from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.	3		ms	
Z <sub>o</sub>	AC Output Impedance	Average value during switching transi- tion. Used for determining series termi- nation value.	40		Ω	

# USBCLK Clock Output (Lump Capacitance Test Load = 20 pF, V<sub>DDC</sub> =2.5V)

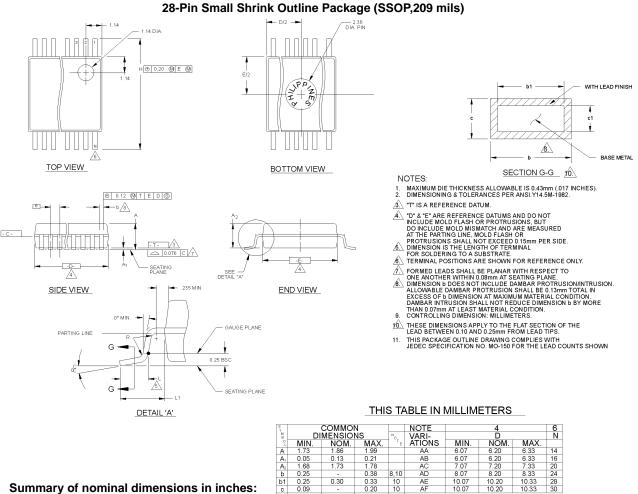
			CPU = 66/100 MHz			
Parameter	Description	Test Condition/Comments	Min.	Тур.	Max.	Unit
t <sub>R</sub>	Output Rise Edge Rate	Measured from 0.4V to 2.0	0.5		2	V/ns
t <sub>F</sub>	Output Fall Edge Rate	Measured from 2.0V to 0.4V	0.5		2	V/ns
t <sub>D</sub>	Duty Cycle	Measured on rising and falling edge at 1.25V	45		55	%
t <sub>JL</sub>	Jitter, Long term	Measured on rising edge at 1.25V. Maximum difference of cycle time between two adjacent cycles.			500	
t <sub>JC</sub>	Jitter, Cycle-to-Cycle	Measured on rising edge at 1.25V. Maximum difference of cycle time between two adjacent cycles.			400	
f <sub>ST</sub>	Frequency Stabilization from Power-up (cold start)	Assumes full supply voltage reached within 1 ms from power-up. Short cycles exist prior to frequency stabilization.			3	ms
Z <sub>o</sub>	AC Output Impedance	Average value during switching transition. Used for determining series termination value.		40		Ω

### **Ordering Information**

Ordering Code	Package Name	Package Type	Temperature Grade
CY24242	PVC	28-pin SSOP (300 mils)	C (Commercial 0 - 70 <sup>0</sup> )



# Package Diagrams

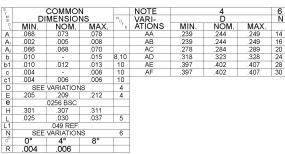


Body Width: 0.296 Lead Pitch: 0.025 Body Length: 0.625 Body Height: 0.102

A₂	1.68	1.73	1.78		
b	0.25	-	0.38	8,10	
b1	0.25	0.30	30 0.33		
С	0.09	-	0.20	10	
c1	0.09	0.15	0.16	10	
D	SEE	VARIATION	is	4	
E	5.20	5.30	5.38	4	
е		0.65 BSC			
Н	7.65	7.80	7.90		
L	0.63	0.75	0.95	5	
L1		1.25 REF.			
N	SEE	VARIATION			
cc	0°	4°	8°		
R	0.09	0.15			

#### \_\_\_\_\_VARIATION AF\_\_\_\_\_ IS DESIGNED BUT NOT TOOLEI

#### THIS TABLE IN INCHES



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Document Title: CY24242 Laser Printer Frequency Synthesizer Document Number: 38-07268							
REV.	ECN NO.	Issue Date	Orig. of Change	Description of Change			
**	110533	10/08/01	SZV	Change from Spec number: 38-01133 to 38-07268			